

S20SC4M

40V 20A

FEATURES

- Tj150°C
- P_{RRSM} avalanche guaranteed
- Small θ_{jc}
- High current capacity

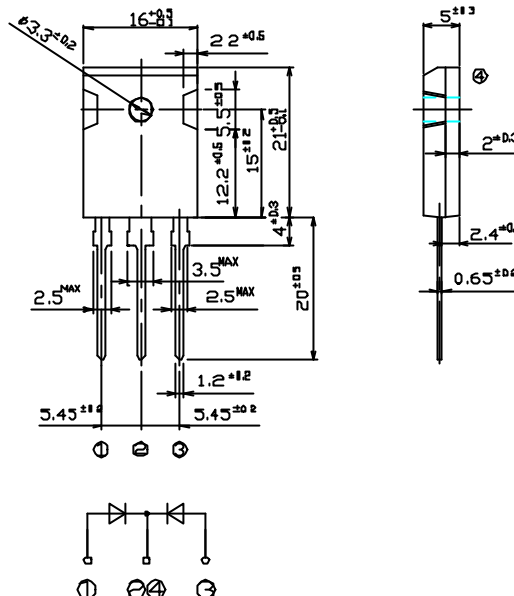
APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS

Case : MTO-3P

Unit : mm



RATINGS

- Absolute Maximum Ratings (If not specified Tc=25°C)

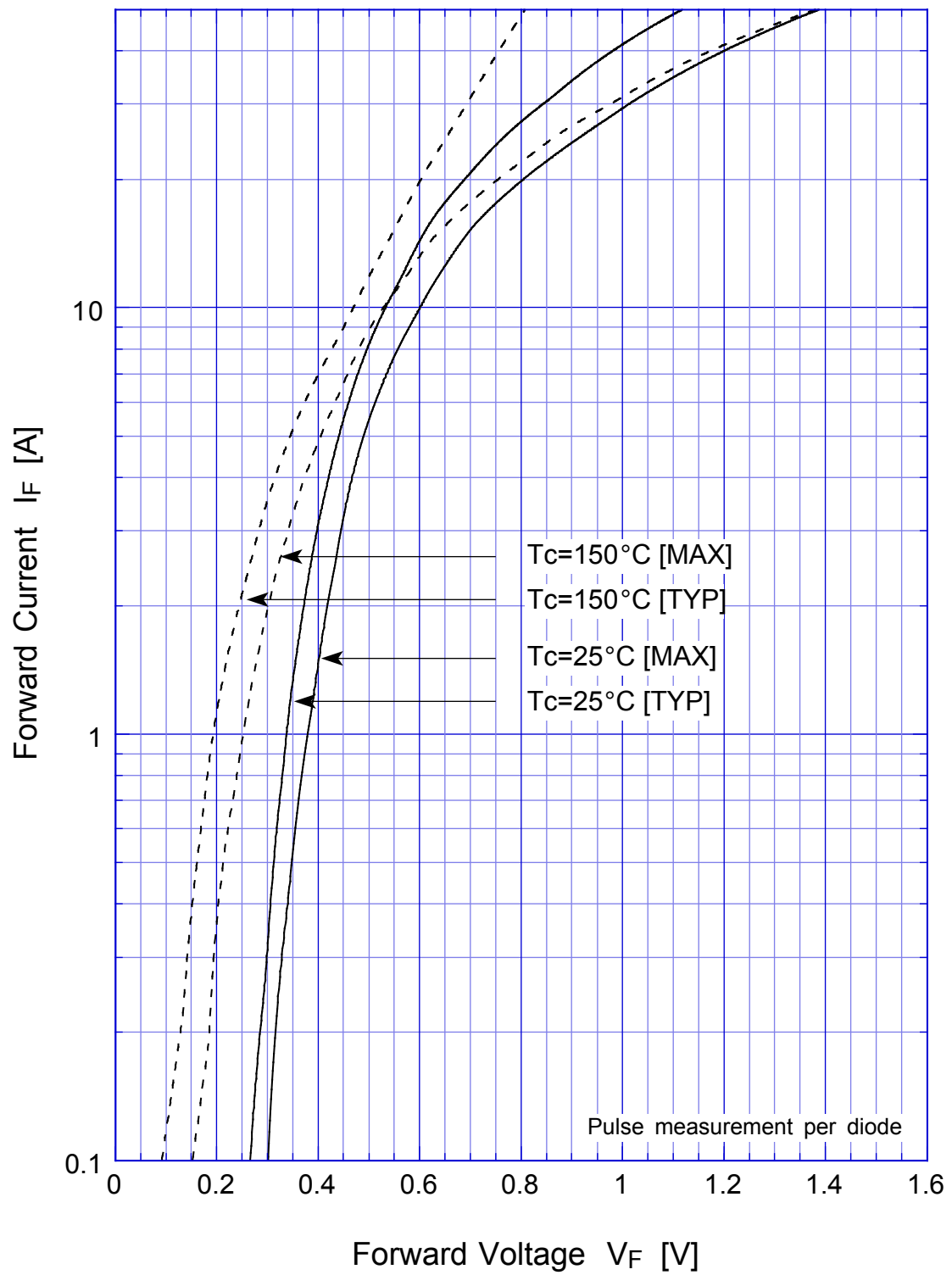
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40~150	°C
Operating Junction Temperature	Tj		150	°C
Maximum Reverse Voltage	V _{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V _{RFSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, Rating for each diode I _O /2, T _c =125°C	20	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, T _j =125°C	170	A
Repetitive Peak Surge Reverse Power	P _{RFSM}	Pulse width 10 μs, Rating of per diode, T _j =25°C	660	W
Mounting Torque	TOR	(Recommended torque 0.5N·m)	0.8	N·m

- Electrical Characteristics (If not specified Tc=25°C)

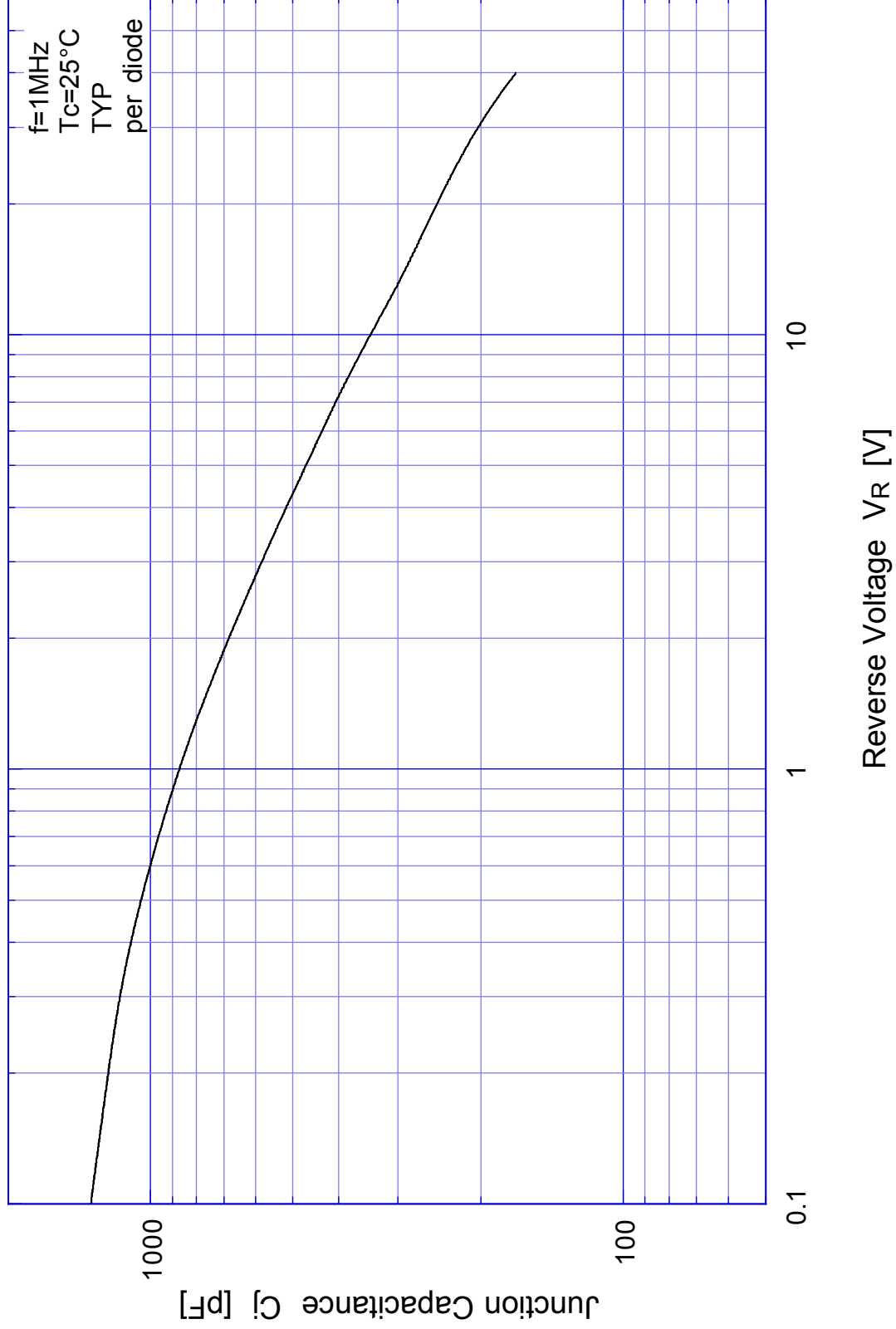
Electrical Characteristics (not specified)		T=25 °C			
Item	Symbol	Conditions		Ratings	Unit
Forward Voltage	V_{F2}	$I_F=10A$,	Pulse measurement, Rating of per diode	Max.0.59	V
Reverse Current	I_R	$V_R=V_{RM}$,	Pulse measurement, Rating of per diode	Max.5	mA
Junction Capacitance	C_j	$f=1MHz$,	$V_R=10V$, Rating of per diode	$T_{vp}.340$	pF
Thermal Resistance	θ_{jc}	junction to case		Max.1.2	°C/W

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Forward Voltage

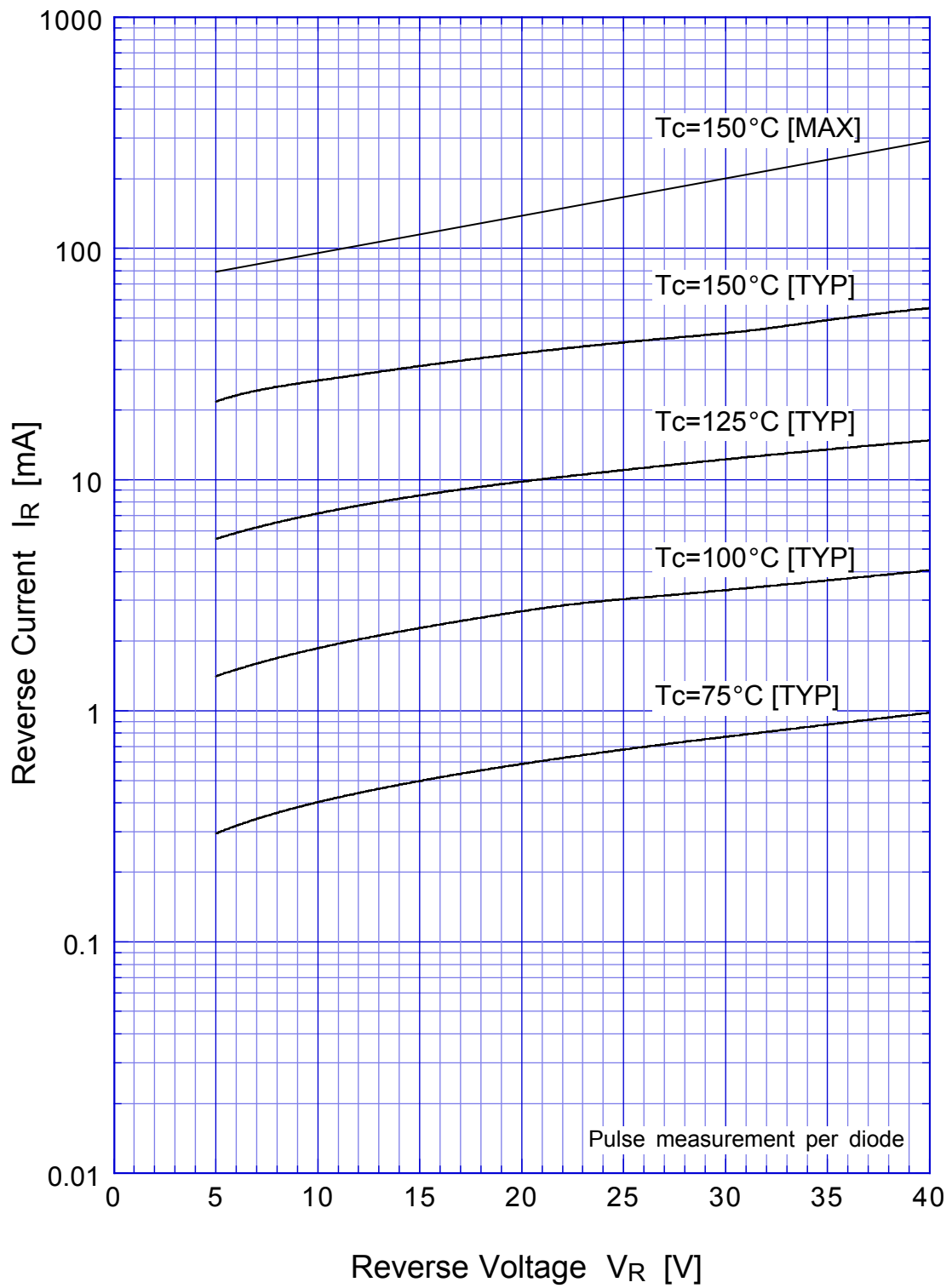


S20SC4M Junction Capacitance

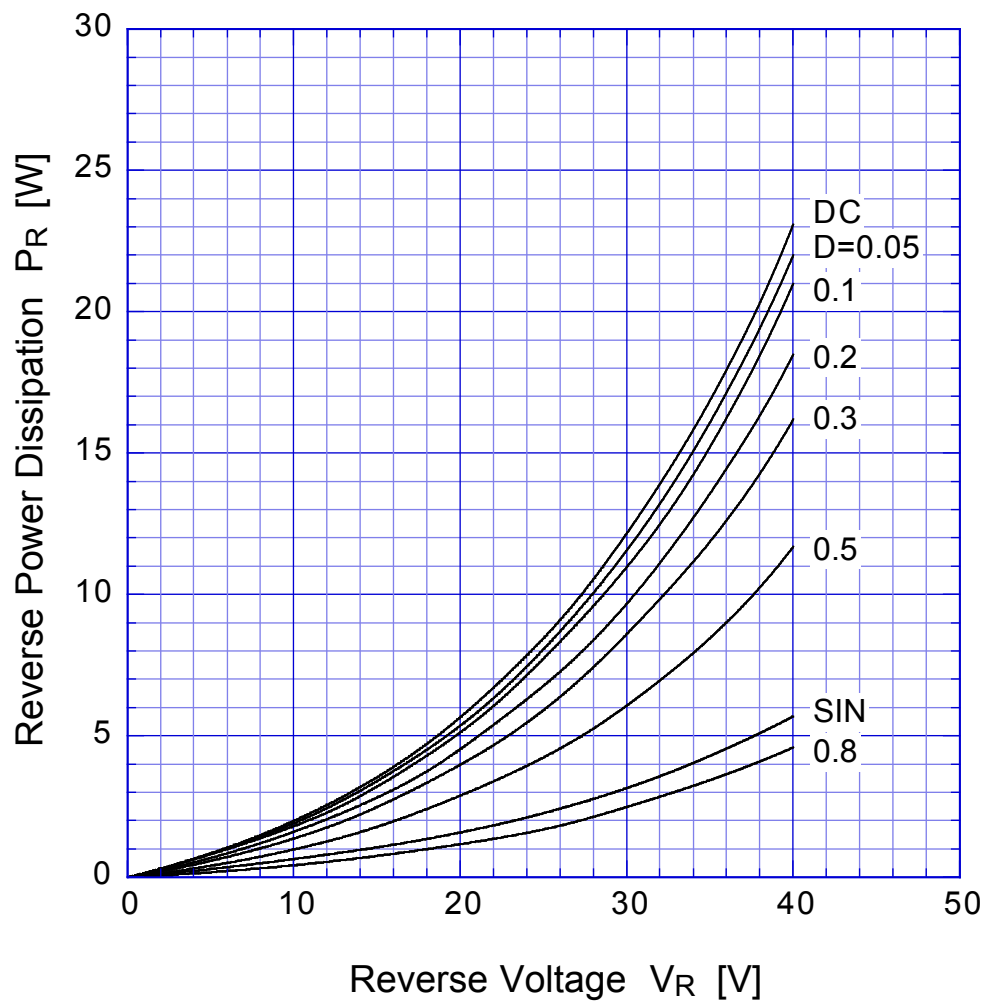


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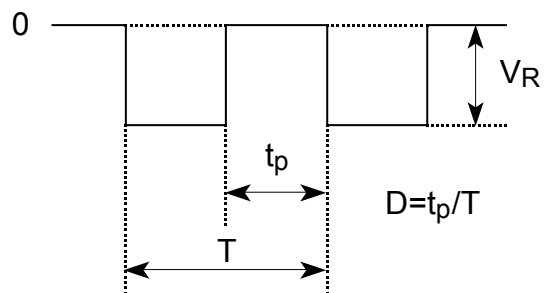
Reverse Current



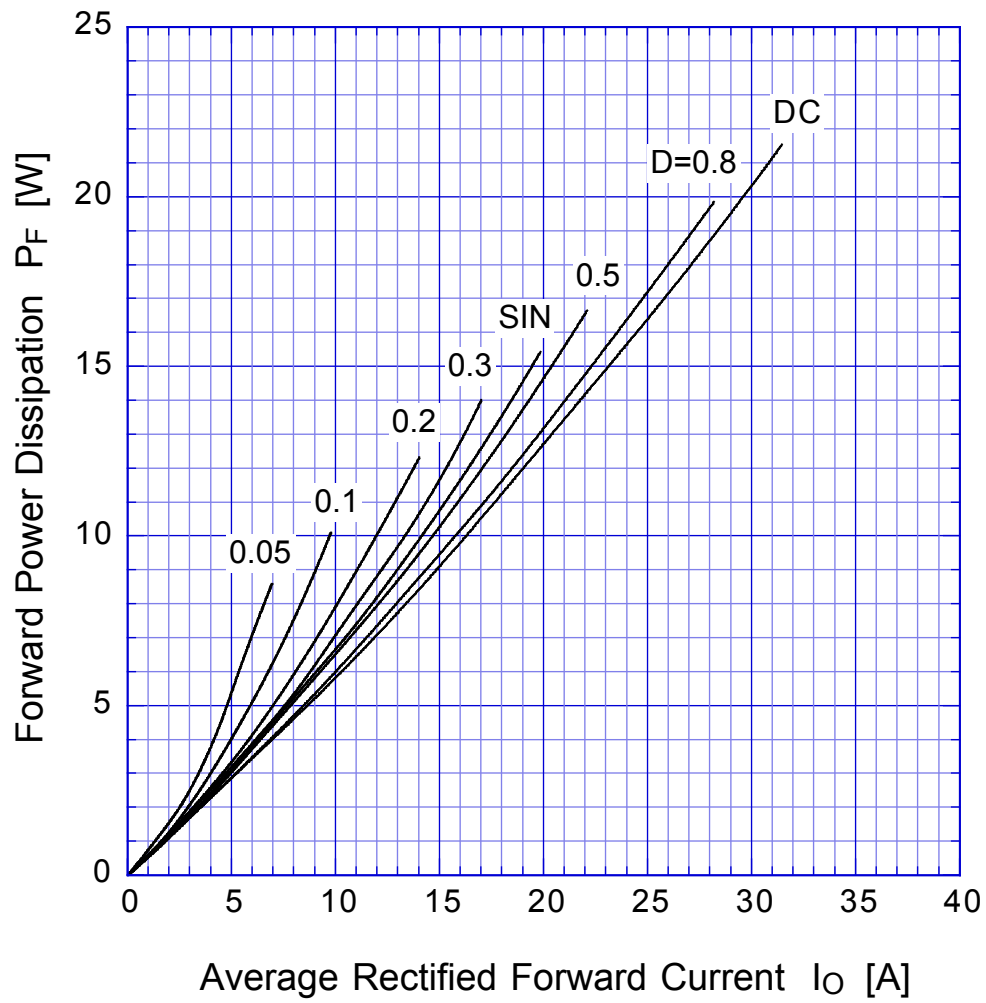
S20SC4M Reverse Power Dissipation



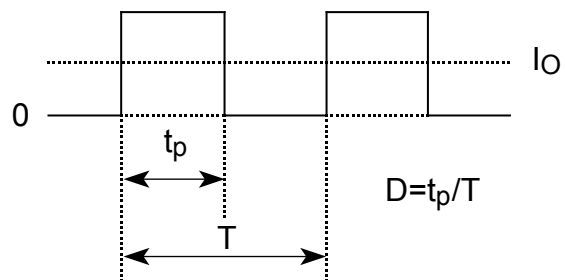
$T_j = 150^\circ\text{C}$



S20SC4M Forward Power Dissipation

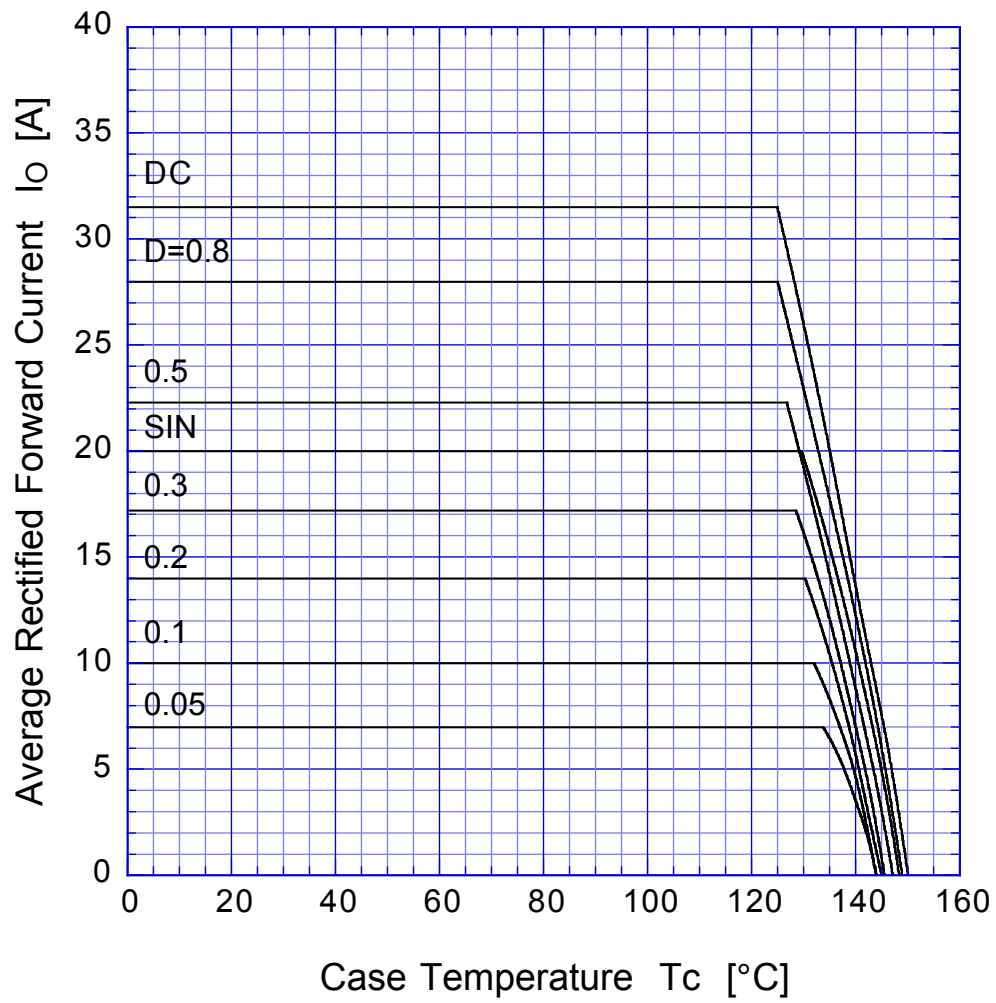


$T_j = 150^\circ\text{C}$

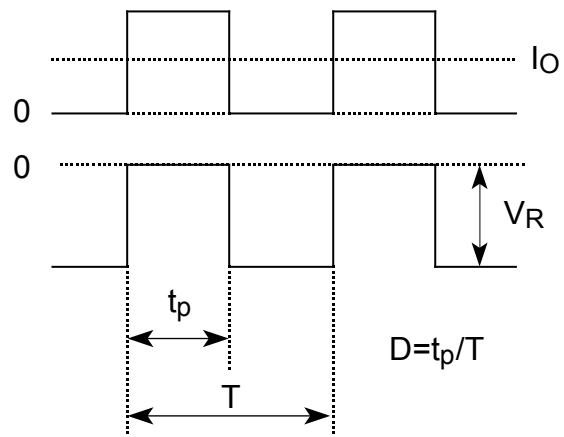


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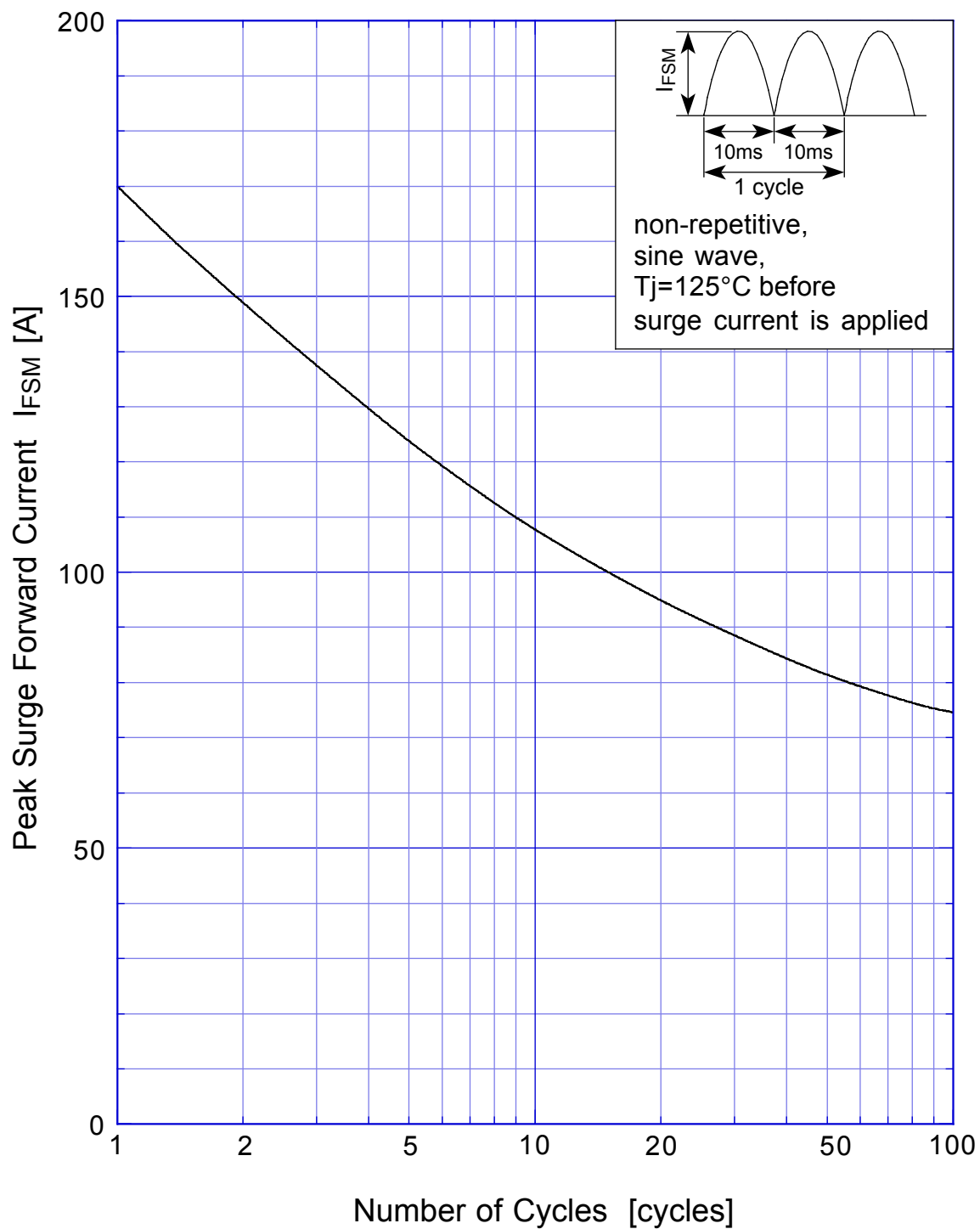
Derating Curve



$V_R = 20V$



S20SC4M Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve

